

Annual report

1st year of PhD in Nanosciences

PhD Student: *Giulia Piccinini*

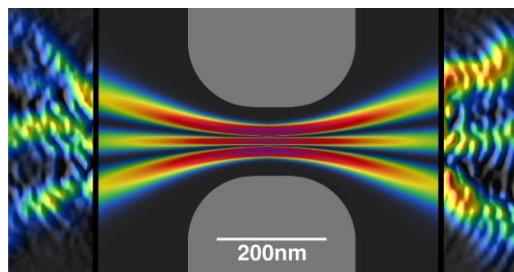
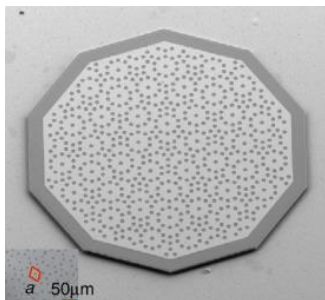
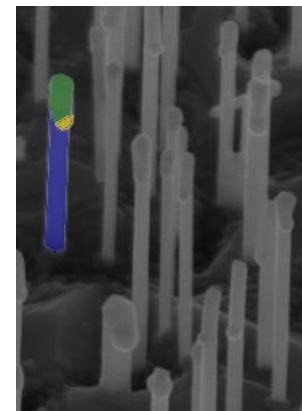
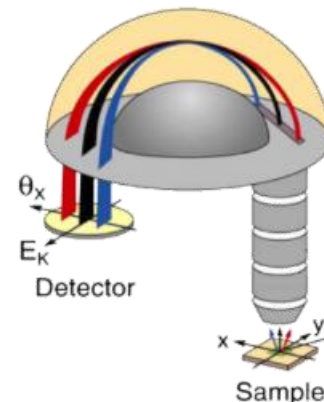
External Supervisor: *Camilla Coletti*

Nanostructured Materials (Dec 2018-May 2019 → 40 h)

S. Heun, L. Sorba

Program:

semiconductors, growth techniques, defects, fabrication, nanostructures, characterization, 2D electron systems, QDs, nanowires



Physics of nanostructures (Apr-Jun 2019 → 44 h)

F. Rossella, M. S. Vitiello, S. Roddaro

Program:

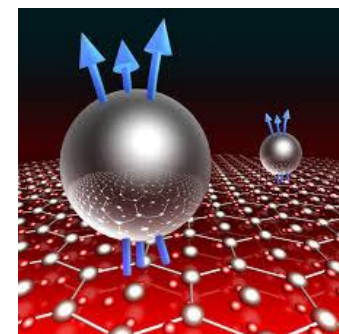
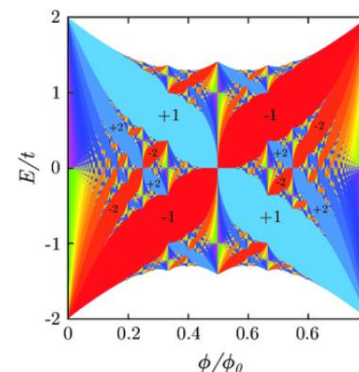
- Optical properties of semiconductor heterostructures
- 1D and 0D systems

Seminars in Condensed matter physics (Apr-Jun 2019 → 44 h)

F. Taddei, G. C. La Rocca, F. Rossella, M. S. Vitiello

Program:

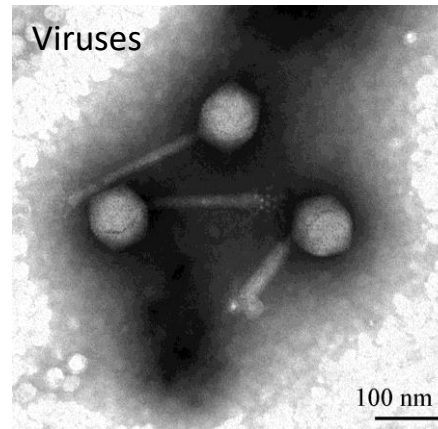
- Topological phases of matter (I. Carusotto and L. Mazza)
- Coherent dynamics and quantum transport in nanostructures (F. Taddei)



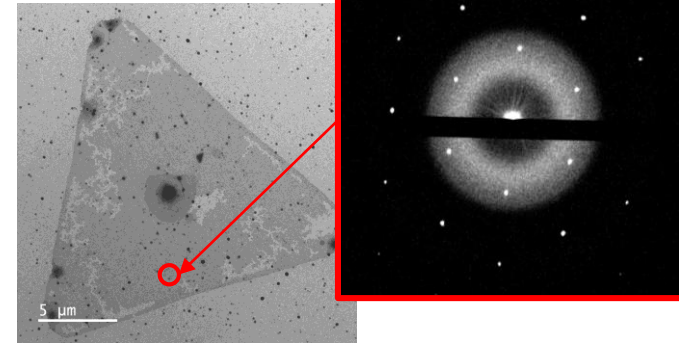
Transmission electron microscopy (Dr. Gemmi lab)



- Imaging (of both biological samples and crystals)
- Diffraction (to identify crystal structures)

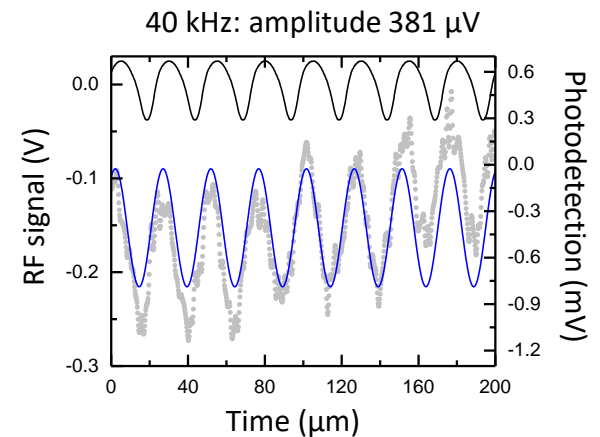
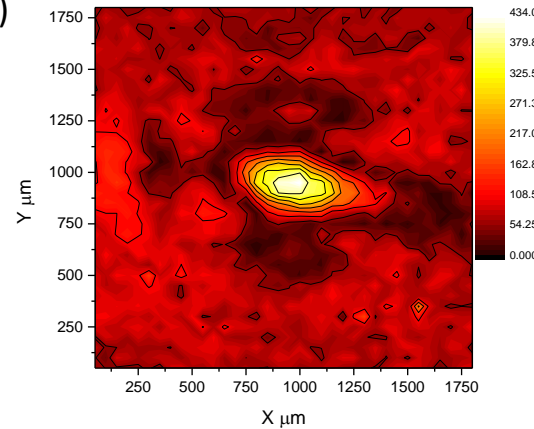
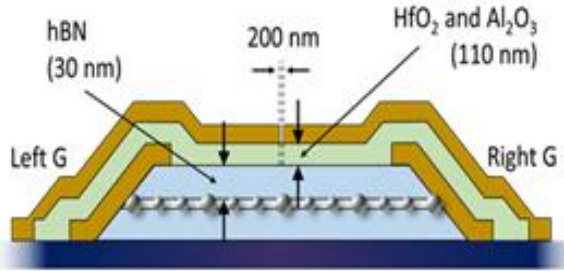


Molybdenum disulfide (MoS_2)



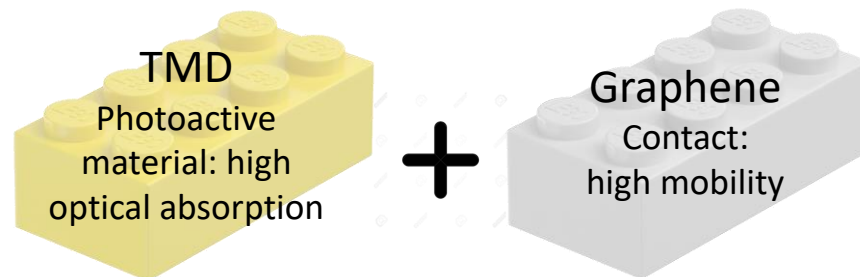
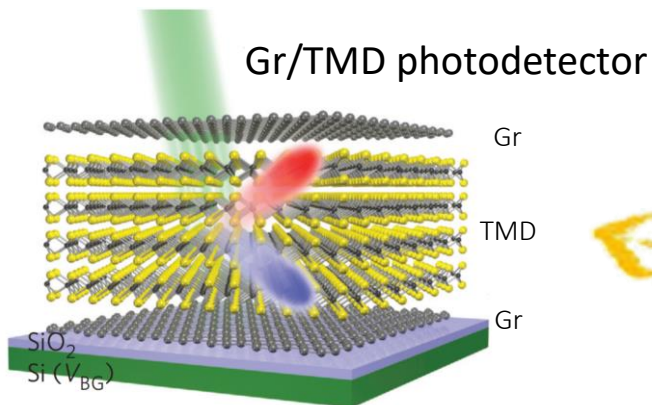
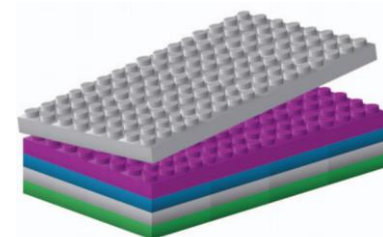
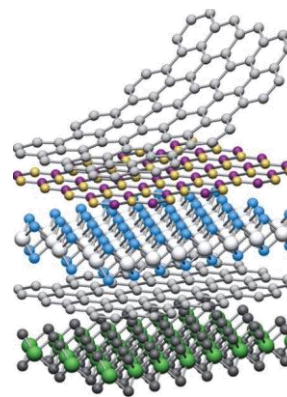
Optical test of nanodetectors operating at THz frequencies (Prof. Vitiello lab)

Graphene THz photodetector (PTE effect)



Graphene/TMDs heterostructures for optoelectronic applications

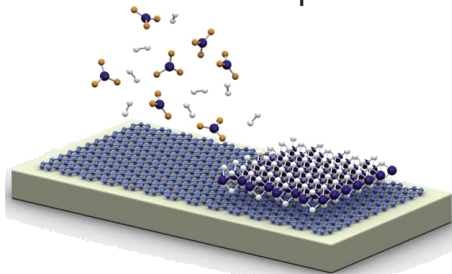
Van der Waals heterostructures (vdWH) → combine layers with different properties to engineer **new functional materials**



X Exfoliation → no control on size, shape, orientation, time consuming, not scalable

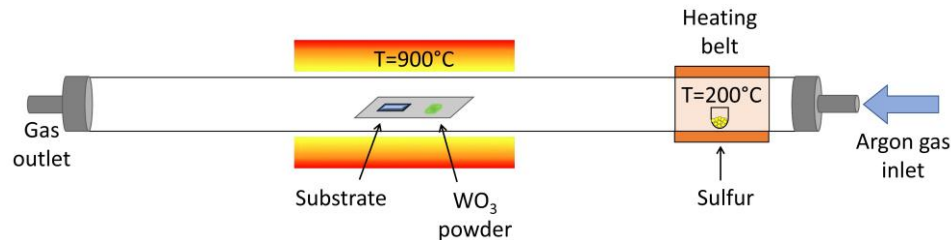


✓ Chemical vapor deposition (CVD) → scalable technique

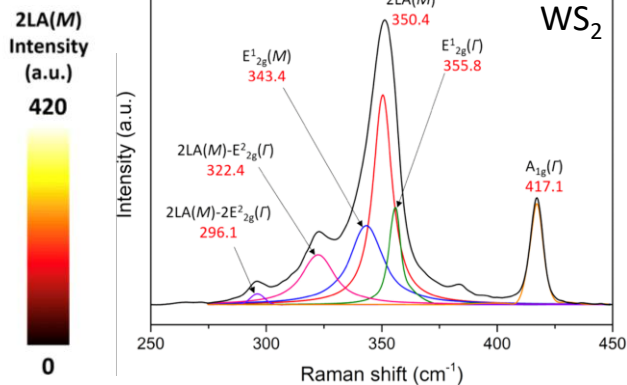
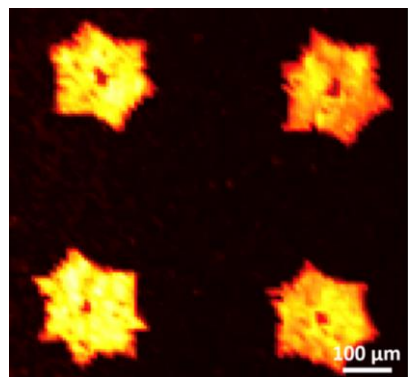


- Synthesis of **high-quality** materials on a **large scale**
- Different **stacking methods** (synthesis + transfer, direct synthesis)
- Materials **characterization, surface science** investigations, etc...
- Devices fabrication and measurements

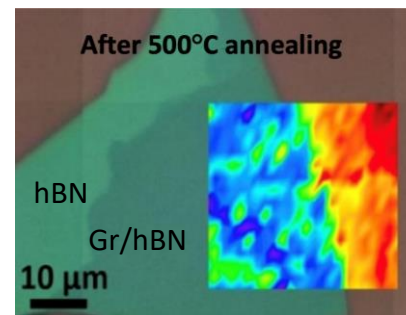
Achieved: Deterministic direct growth of WS₂ on CVD graphene arrays



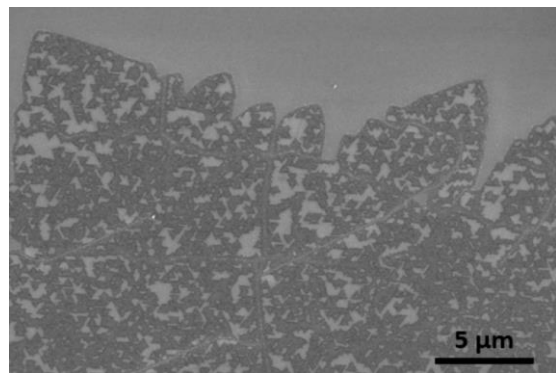
G. Piccinini *et al*
2D Mater. (2019)
<https://doi.org/10.1088/2053-1583/ab49f0>



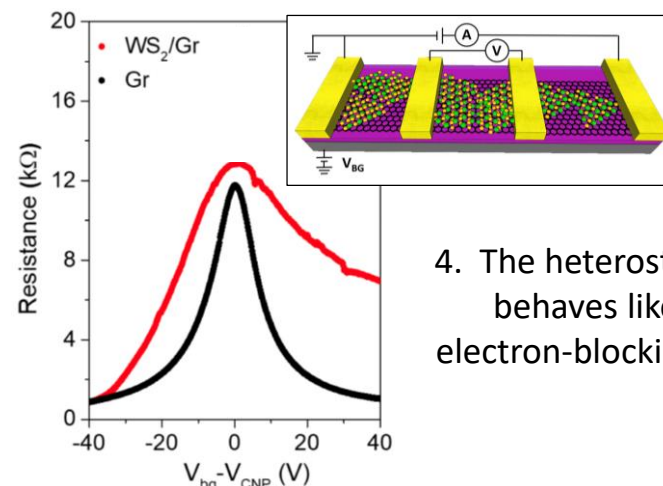
Graphene 2D peak width



3. Graphene is doped (interaction with SiO₂)
↓
hBN: good protective substrate



1. Development of an approach for monolayer WS₂ on graphene arrays
2. Selective growth on graphene (i.e., not on SiO₂)

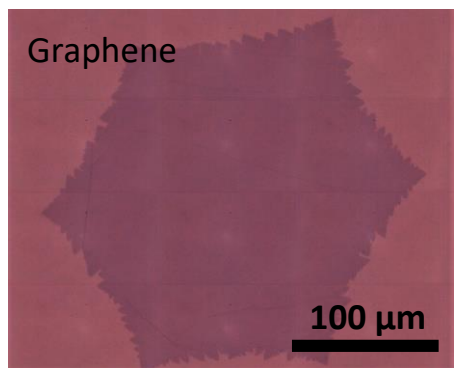


4. The heterostructure behaves like an electron-blocking layer

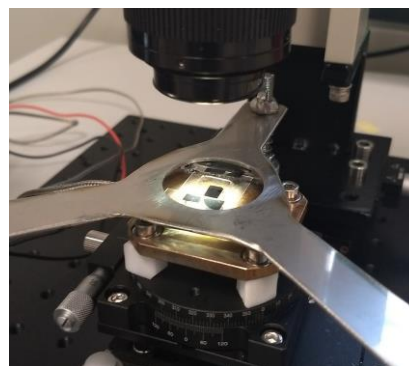
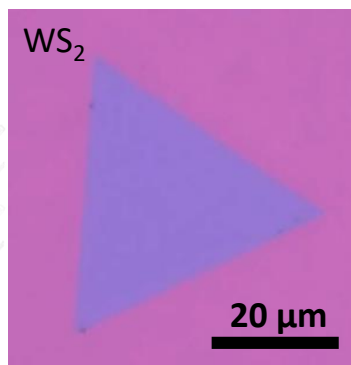
Next steps

Aim: high-performing optoelectronic devices (e.g., graphene/WS₂ photodetectors)

- **Mechanical stacking** of CVD monolayer materials and characterization



+



micromechanical stage

A preliminary Raman characterization revealed that the quality of graphene is preserved after the stacking process

- Devices photodetection performances → **photocurrent measurements**

- Different **rotation angles** between the materials

- **Interfaces, band alignments and charge transfer mechanisms**

- LEED
- Time-resolved ARPES
- Pump-probe reflectance spectroscopy

